Notice of Allowability	Application No.	No. Applicant(s)	
	10/826,980	STEFANOV ET AL.	
	Examiner	Art Unit	
	Tu-Tu Ho	2818	
The MAILING DATE of this communication apperall claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	ears on the cover sheet wit (OR REMAINS) CLOSED in or other appropriate commu GHTS. This application is s	h the correspondence address this application. If not included nication will be mailed in due course. THIS	
1. X This communication is responsive to Paper filed 04/16/200	<u>4</u> .		
2. X The allowed claim(s) is/are <u>1-23</u> .			
3. The drawings filed on 16 April 2004 are accepted by the Ex	kaminer.		
 4. Acknowledgment is made of a claim for foreign priority unally all b) Some* c) None of the: Certified copies of the priority documents have Certified copies of the priority documents have Copies of the certified copies of the priority documents have * Copies of the certified copies of the priority documents have international Bureau (PCT Rule 17.2(a)). 	been received. been received in Application	n No	ł
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		a reply complying with the requirements	
5. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give			
6. ☐ CORRECTED DRAWINGS (as "replacement sheets") mus (a) ☐ including changes required by the Notice of Draftspers 1) ☐ hereto or 2) ☐ to Paper No./Mail Date (b) ☐ including changes required by the attached Examiner's Paper No./Mail Date Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in the state of the paper No./Mail DFORMATION about the depo	on's Patent Drawing Review s Amendment / Comment or .84(c)) should be written on the header according to 37 CF	in the Office action of the drawings in the front (not the back) of R 1.121(d). ERIAL must be submitted. Note the	
attached Examiner's comment regarding REQUIREMENT	FOR THE DEPOSIT OF BIC	DLOGICAL MATERIAL.	
Attachment(s) 1. ⊠ Notice of References Cited (PTO-892)	5. ☐ Notice of In	formal Patent Application (PTO-152)	
Notice of Neterences Cited (PTO-092) Notice of Draftperson's Patent Drawing Review (PTO-948)	6. Interview S	ımmary (PTO-413),	
 3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 04/16/2004 4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material 	98), 7. 🗌 Examiner's	Mail Date Amendment/Comment Statement of Reasons for Allowance Tu-Tu Ho July 17, 2005	

DETAILED ACTION

Allowable Subject Matter

1. Claims 1-23 are allowable over the prior art of record.

The following is an examiner's statement of reasons for allowance: The prior art of record fails to teach or render obvious a flip chip light emitting diode having all exclusive limitations as recited in claims 1, 11, and 20, including a light-transmissive substrate; a base semiconductor layer disposed on the light-transmissive substrate; light-emitting micromesa disposed on the base semiconductor layer; a conductive contact structure on the base semiconductor layer; a first electrode in electrical communication with the conductive contact structure; and a second electrode over the light-emitting micromesa; the conductive contact structure either: being a conductive mesh, or: including a bonding pad region and at least one conductive finger extending from the bonding pad region to effect electrical communication between the first electrode and the light-emitting micromesa, wherein the first electrode is a first conductivity type electrode and the base semiconductor layer is of the first conductivity type; and the light-emitting micromesa either: being disposed in openings of the conductive mesh, each light-emitting micromesa having a topmost layer of a conductivity type opposite to that of the base semiconductor layer, or: the conductive mesh deposited on the base semiconductor layer in trenches between the light-emitting micromesa, the light-emitting micromesa having an active area, the conductive mesh defining a continuous electrode that is co-extensive with the active area, and the second electrode being a continuous electrode and contacting the tops of the lightemitting micromesa and being co-extensive with the active area;

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and wherein the limitation "light emitting diode" has been interpreted in light of the specification; for example, the claimed light emitting diode is not the same as, for example, a light emitting diode array, for example, used in print heads.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

2. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Gupta et al. U.S. Patent 6,274,293 discloses a flexible metallic mesh functioning as photonic bandgap structures for optoelectronic devices.

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tu-Tu Ho whose telephone number is (571) 272-1778. The examiner can normally be reached on 6:30 am - 5:00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, DAVID NELMS can be reached on (571) 272-1787. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Tu-Tu Ho July 17, 2005